

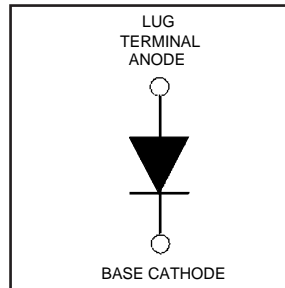
# HFA180NH40

HEXFRED™

Ultrafast, Soft Recovery Diode

## Features

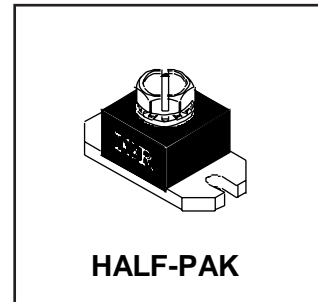
- Reduced RFI and EMI
- Reduced Snubbing
- Extensive Characterization of Recovery Parameters



$V_R = 400V$
$V_F(\text{typ.})^{\textcircled{3}} = 1.1V$
$I_{F(AV)} = 180A$
$Q_{rr}(\text{typ.}) = 420nC$
$I_{RRM}(\text{typ.}) = 8.7A$
$t_{rr}(\text{typ.}) = 45ns$
$di_{(rec)}/dt(\text{typ.})^{\textcircled{3}} = 280A/\mu s$

## Description

HEXFRED™ diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and di/dt simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.



## Absolute Maximum Ratings (per Leg)

	Parameter	Max.	Units
$V_R$	Cathode-to-Anode Voltage	400	V
$I_F @ T_C = 25^\circ C$	Continuous Forward Current	321	A
$I_F @ T_C = 100^\circ C$	Continuous Forward Current	160	
$I_{FSM}$	Single Pulse Forward Current <sup>①</sup>	1200	
$E_{AS}$	Non-Repetitive Avalanche Energy <sup>②</sup>	1.4	mJ
$P_D @ T_C = 25^\circ C$	Maximum Power Dissipation	625	W
$P_D @ T_C = 100^\circ C$	Maximum Power Dissipation	250	
$T_J$	Operating Junction and	-55 to +150	°C
$T_{STG}$	Storage Temperature Range		

## Thermal - Mechanical Characteristics

	Parameter	Min.	Typ.	Max.	Units
$R_{thJC}$	Junction-to-Case	—	—	0.20	°C/W
$R_{thCS}$	Case-to-Sink, Flat, Greased Surface	—	0.15	—	K/W
$Wt$	Weight	—	26 (0.9)	—	g (oz)
	Mounting Torque <sup>④</sup>	15 (1.7)	—	25 (2.8)	lbf·in
	Terminal Torque	30 (3.4)	—	40 (4.6)	(N·m)
	Vertical Pull	—	—	35	lbf·in
	2 inch Lever Pull	—	—	35	

**Note:** <sup>①</sup> Limited by junction temperature  
<sup>②</sup> L = 100μH, duty cycle limited by max  $T_J$   
<sup>③</sup> 125°C

<sup>④</sup> Mounting surface must be smooth, flat, free of burrs or other protrusions. Apply a thin even film of thermal grease to mounting surface. Gradually tighten each mounting bolt in 5-10 lbf·in steps until desired or maximum torque limits are reached. Module

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PD-2.452 rev. B 03/99

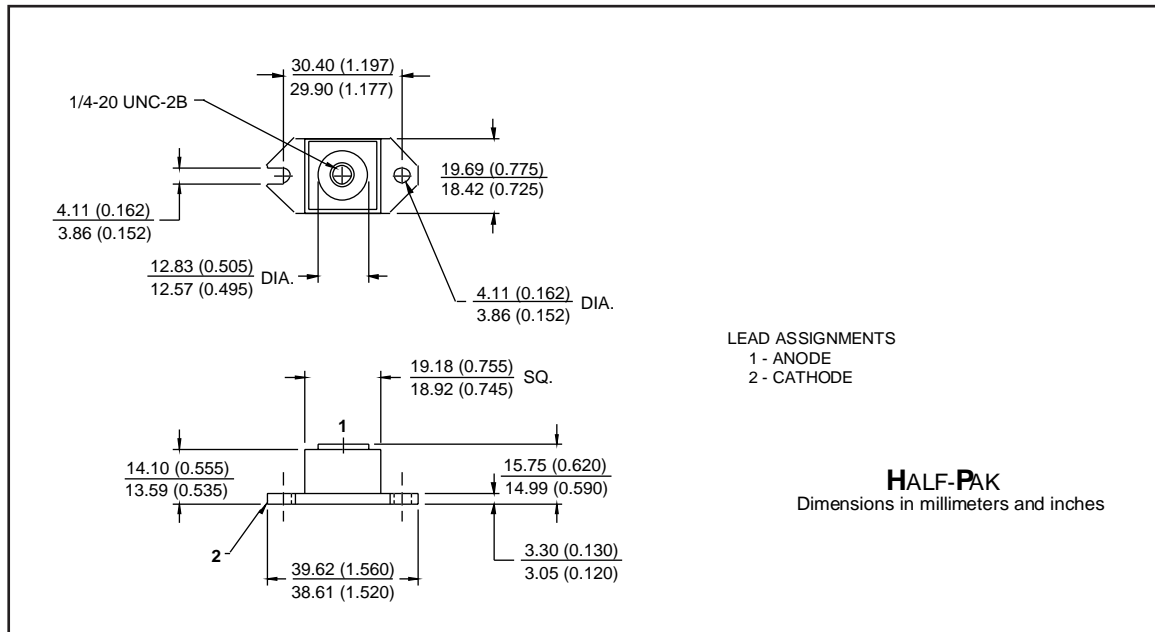
International  
**IOR** Rectifier

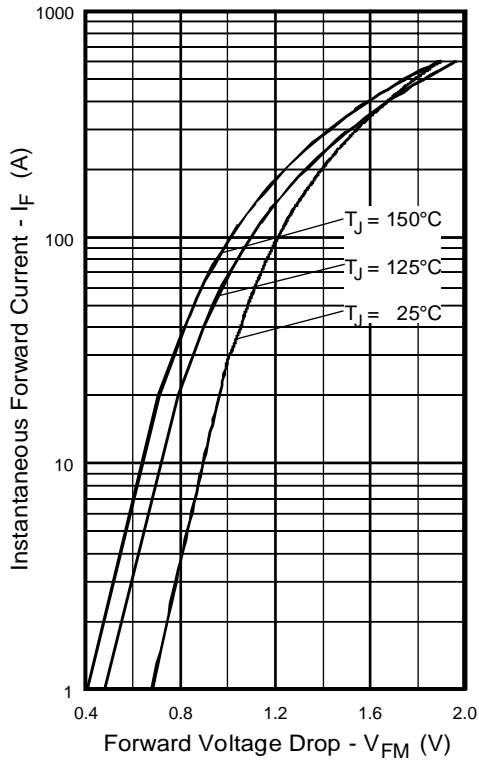
## Electrical Characteristics (per Leg) @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Test Conditions
$V_{BR}$	Cathode Anode Breakdown Voltage	400	—	—	V	$I_R = 100\mu\text{A}$
$V_{FM}$	Max Forward Voltage See Fig. 1	—	1.10	1.35	V	$I_F = 180\text{A}$
		—	1.40	1.65		$I_F = 360\text{A}$
		—	1.10	1.30		$I_F = 180\text{A}, T_J = 125^\circ\text{C}$
$I_{RM}$	Max Reverse Leakage Current See Fig. 2	—	2.0	12	$\mu\text{A}$	$V_R = V_R \text{ Rated}$
		—	3.0	16	$\text{mA}$	$T_J = 125^\circ\text{C}, V_R = 320\text{V}$
$C_T$	Junction Capacitance See Fig. 3	—	370	500	$\text{pF}$	$V_R = 200\text{V}$
$L_S$	Series Inductance	—	5.0	—	$\text{nH}$	From top of terminal hole to mounting plane

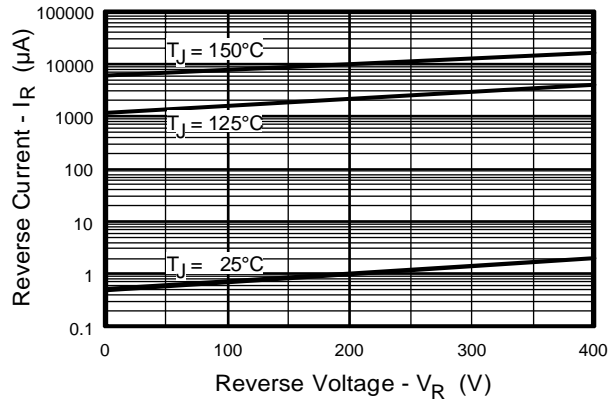
## Dynamic Recovery Characteristics (per Leg) @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Test Conditions	
$t_{rr}$	Reverse Recovery Time	—	45	—	ns	$I_F = 1.0\text{A}, di_f/dt = 200\text{A}/\mu\text{s}, V_R = 30\text{V}$ $T_J = 25^\circ\text{C}$	
$t_{rr1}$	See Fig. 5	—	90	140			$T_J = 125^\circ\text{C}$
$t_{rr2}$		—	290	440			$T_J = 125^\circ\text{C}$
$I_{RRM1}$	Peak Recovery Current	—	8.7	20	A	$T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	
$I_{RRM2}$	See Fig. 6	—	18	30			$V_R = 200\text{V}$
$Q_{rr1}$	Reverse Recovery Charge	—	420	1100	nC	$T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	
$Q_{rr2}$	See Fig. 7	—	2600	7000			$di_f/dt = 200\text{A}/\mu\text{s}$
$di_{(rec)M}/dt1$	Peak Rate of Fall of Recovery Current	—	300	—	$\text{A}/\mu\text{s}$	$T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	
$di_{(rec)M}/dt2$	During $t_b$ See Fig. 8	—	280	—			

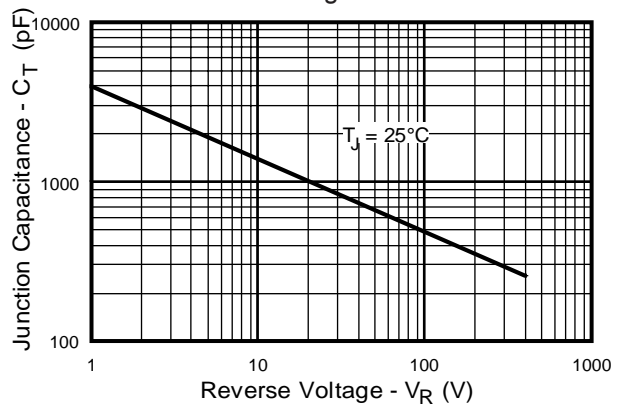




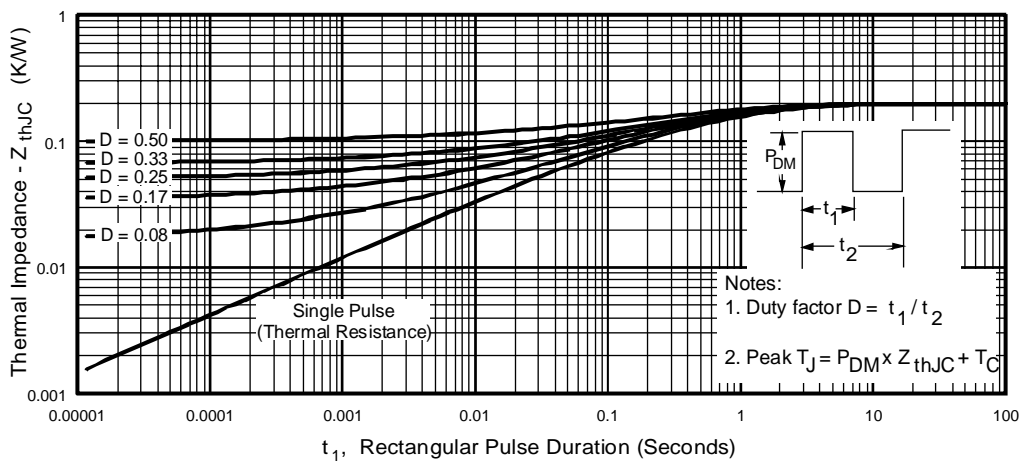
**Fig. 1** - Maximum Forward Voltage Drop vs. Instantaneous Forward Current



**Fig. 2** - Typical Reverse Current vs. Reverse Voltage



**Fig. 3** - Typical Junction Capacitance vs. Reverse Voltage

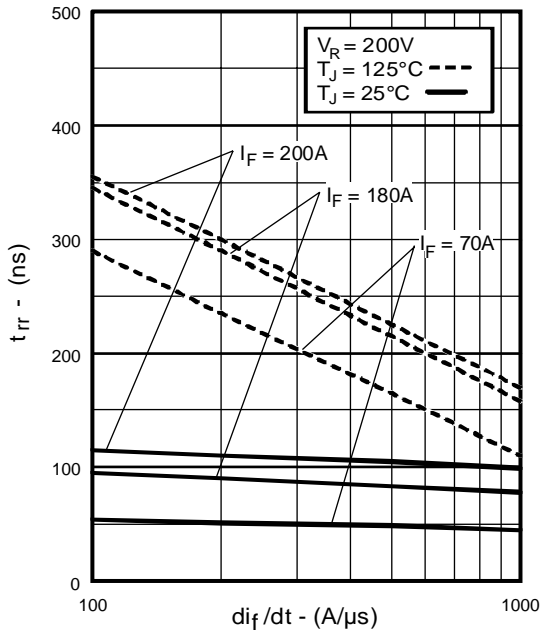


**Fig. 4** - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

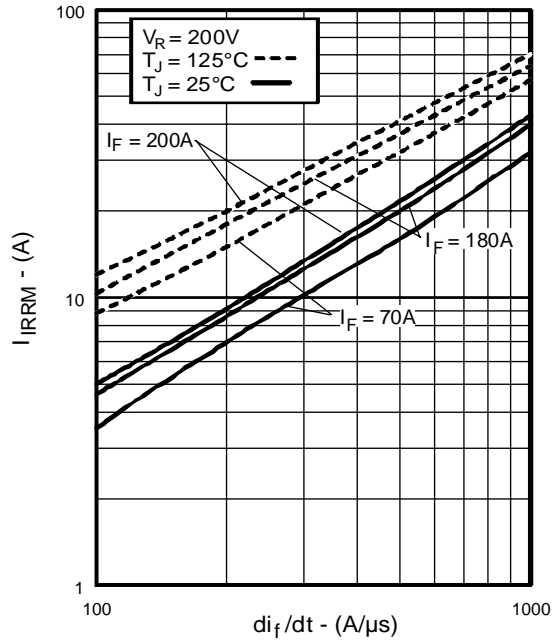
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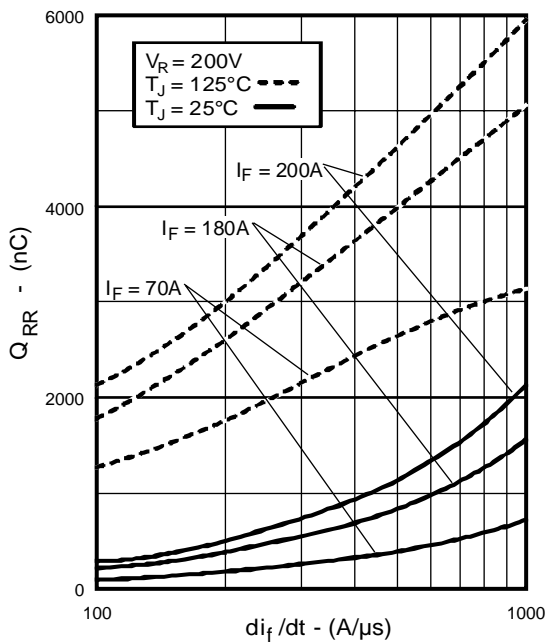
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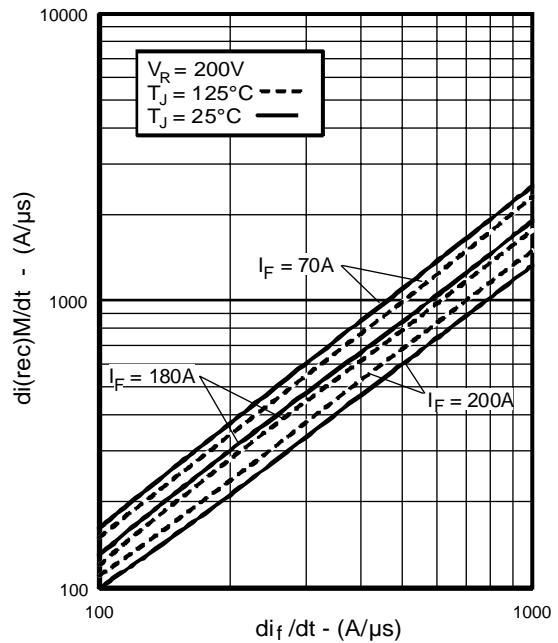
**Fig. 5** - Typical Reverse Recovery vs.  $di_f/dt$



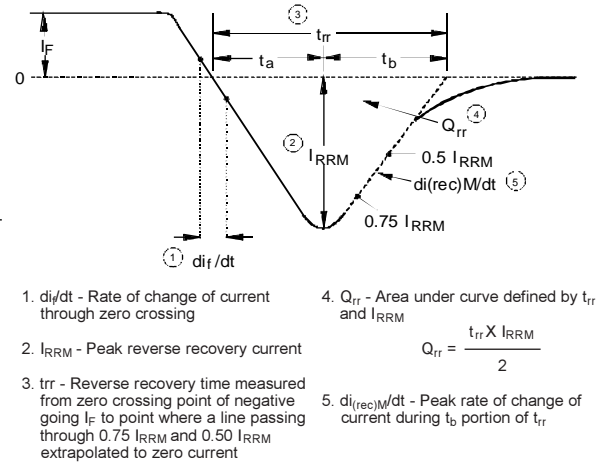
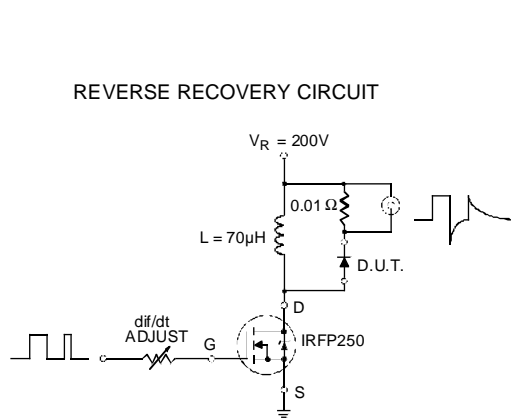
**Fig. 6** - Typical Recovery Current vs.  $di_f/dt$



**Fig. 7** - Typical Stored Charge vs.  $di_f/dt$

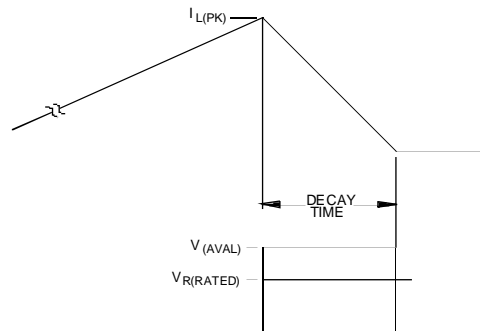
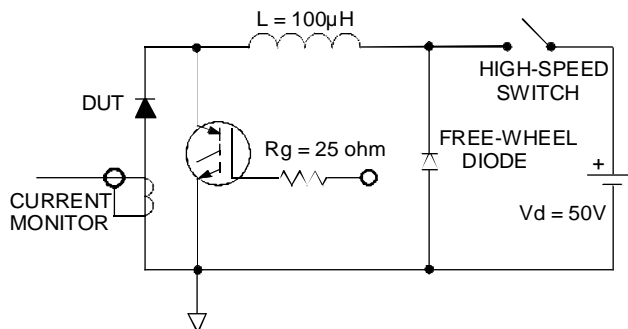


**Fig. 8** - Typical  $di_{(rec)M}/dt$  vs.  $di_f/dt$



**Fig. 9 - Reverse Recovery Parameter Test Circuit**

**Fig. 10 - Reverse Recovery Waveform and Definitions**



**Fig. 11 - Avalanche Test Circuit and Waveforms**